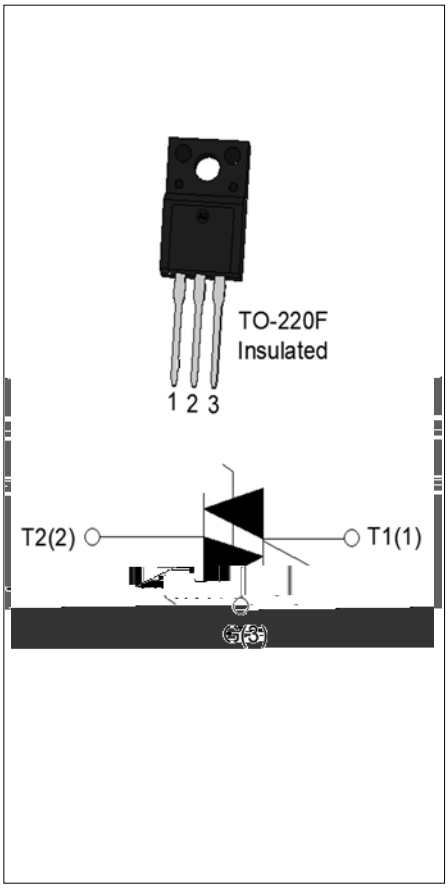
ACJT08F-800CW 8A TRIAC

Rev.A.1.1

DESCRIPTION:

The ACJT08F-800CW triac is suitable for general purpose AC switching. It can be used as an ON/OFF function in applications such as heating regulation, induction motor starting circuits, for phase control operation in light dimmers, motor speed controllers. The ACJT08F-800CW embeds a TVS structure to absorb the inductive turn-off energy such as those described in the IEC 61000-4-5 standards. By using an external plastic package, ACJT08F-800CW provides a rated insulation voltage of 2000 VRMS, complying with UL standards (File ref: E252906). Package TO-220F is RoHS compliant.



MAIN FEATURES

Symbol	Value	Unit
$I_{T(RMS)}$	8	A
V_{DRM} /V_{RRM}	800	V
I_{GT} / /	35/35/35	mA

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Storage junction temperature range	T_{stg}	-40-150	
Operating junction temperature range	T_j	-40-125	
Repetitive peak off-state voltage (T_j=25)	V_{DRM}	800	V
Repetitive peak reverse voltage (T_j=25)	V_{RRM}	800	V
RMS on-state current ($T_C \leq$ 94)	$I_{T(RMS)}$	8	A
Non repetitive surge peak on-state current (full cycle , t_p=20ms , T_j=25)	I_{TSM}	80	A
Non repetitive surge peak on-state current (full cycle , t_p=16.6ms , T_j=25)		88	
I^2t value for fusing (t_p=10ms , T_j=25)	I^2t	32	A^2s
Critical rate of rise of on-state current (I_G=2 × I_{GT} , f=100Hz , T_j=125)	dI/dt	100	A/μs
Peak gate current (t_p=20μs , T_j=125)	I_{GM}	4	A

Average gate power dissipation (T_j=125)	$P_{G(AV)}$	0.5	W
Peak gate power	P_{GM}	10	W
Peak pulse voltage (T_j=25 ; non-repetitive,off-state;FIG.7)	V_{pp}	2.75	kV

LECTRICAL CHARACTERISTICS (T_j=25 unless otherwise specified)

Symbol	Test Condition	Quadrant	Value		Unit
I_{GT}	V_D =12V R_L =33Ω	- -	MAX.	35	mA
V_{GT}		- -	MAX.	1	V
V_{GD}	V_D =V_{DRM} T_j =125 R_L =3.3kΩ	- -	MIN.	0.2	V
I_L	I_G =1.2I_{GT}	-	MAX.	35	mA
				55	
I_H	I_T =100mA		MAX.	30	mA
dV/dt	V_D=540V Gate Open T_j =125		MIN.	2600	V/μs
(dI/dt)c	(dV/dt)c=10V/μs, T_j=125		MIN.	10	A/ms
t_{on}	I_G=40mA I_A=200mA I_R=20mA T_j=25		TYP.	3	μs
t_{off}				30	
V_{CL}	I_{CL}=0.1mA t_p=1ms		MIN.	850	V

TATIC CHARACTERISTICS

Symbol	Parameter		Value(MAX.)	Unit
V_{TM}	I_{TM} =10A t_p=380μs	T_j=25	1.45	V
V_{TO}		T_j=125	h 0.78	V r
R_D	Dynamic resistance	T_j=125	48	mΩ
I_{DRM}	V_D =V_{DRM} V_R =V_{RRM}	T_j=25	5	μA
I_{RRM}		T_j=125	0.5	mA

THERMAL RESISTANCES

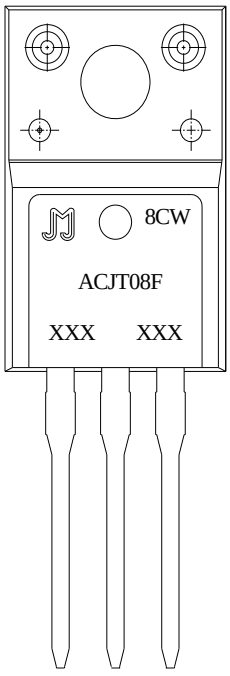
Symbol	Parameter	Value	Unit

ORDERING INFORMATION

AC J T 08 F -800 CW

- AC: AC switch
- J: JieJie Microelectronics Co., Ltd.
- T: Triacs
- 08: $I_{T(RMS)}$:8A
- F: F:TO-220F(Ins)
- -800: 800:V_{DRM} /V_{RRM} ≥ 800V
- CW: I_{GT1-3} ≤ 35mA

MARKING



XXX XXX

- XXX: Year
- XXX: Month
- XXX: Production Code

FIG.1: Maximum power dissipation versus RMS on-state current

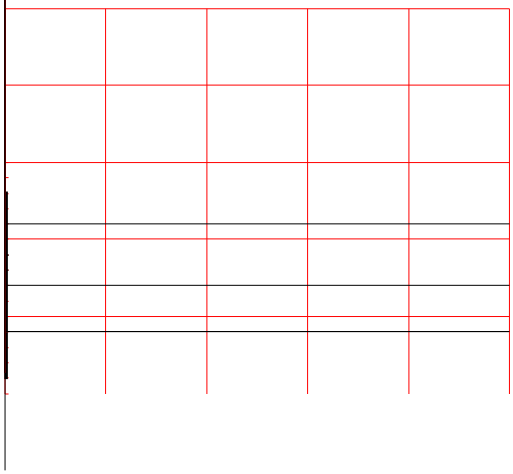
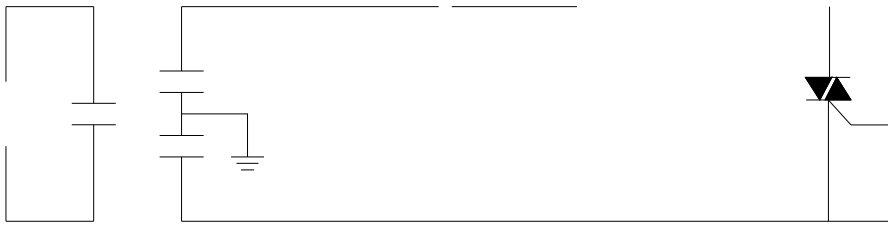


FIG.2: RMS on-state current versus case temperature

FIG.7 Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



ORDERING INFORMATION

Order code	Voltage V_{DRM}/V_{RRM} (V)	IGT(mA)	Package	Base qty. (pcs)	Delivery mode
ACJT08F-800CW	800	35	TO-220F(Ins)	50	Tube

(o ∫ 5 0

Document Revision History

Date	Revision	Ch]

Information furnished in this document is believed to be accurate and reliable. However, Jiangsu JieJie Microelectronics Co., Ltd. assumes no responsibility for the consequences of use without consideration for such information nor use beyond it. Information mentioned in this document is subject to change without notice, apart from that when an agreement is signed, Jiangsu JieJie complies with the agreement.
Products and information provided in this document have no infringement of patents. Jiangsu JieJie assumes no responsibility for any infringement of other rights of third parties which may result from the use of such products and information. This document supersedes and replaces all information previously supplied.

is a registered trademark of Jiangsu JieJie Microelectronics Co., Ltd.

Copyright © 2025 Jiangsu JieJie Microelectronics Co., Ltd. All rights reserved.